

AD-A157 140

HIGH DENSITY EXCITONIC STATE IN TWO-DIMENSIONAL
MULTIQUANTUM WELLS(CU) MASSACHUSETTS INST OF TECH
CAMBRIDGE FRANCIS BITTER NATIONAL MAGNET LAB

1/1

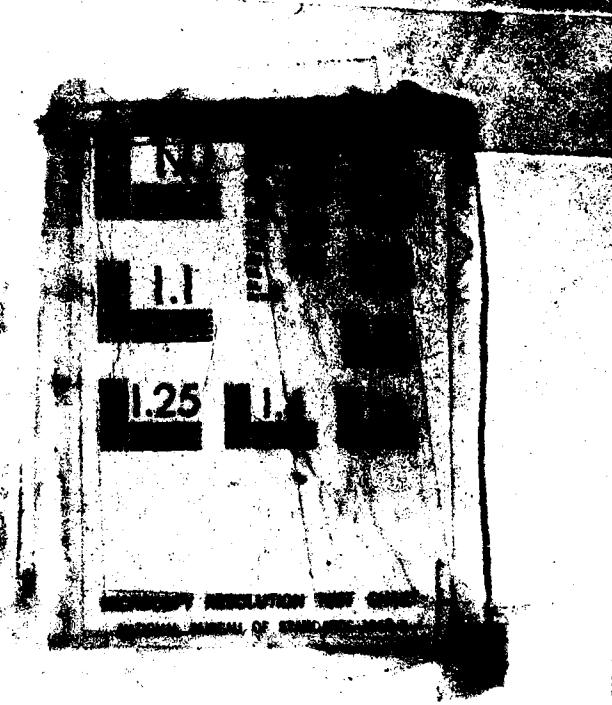
UNCLASSIFIED

H Q LE ET AL. 1984 N00014-84-K-0431

F/G 20/12

NL

END
FILED
OIC.



AD-A157 140

DTIC FILE COPY

SECURITY CLASSIFICATION OF THIS PAGE (When Data Entered)

(2)

REPORT DOCUMENTATION PAGE		READ INSTRUCTIONS BEFORE COMPLETING FORM
1. REPORT NUMBER	2. GOVT ACCESSION NO.	3. RECIPIENT'S CATALOG NUMBER
4. TITLE (and Subtitle) High Density Excitonic State in Two-dimensional Multiple Quantum Wells MULTIQUANTUM		5. TYPE OF REPORT & PERIOD COVERED Final, 1984
6. AUTHOR(s) H.Q. Le, B. Lax, B.A. Vojak, A.R. Calawa		7. PERFORMING ORG. REPORT NUMBER 84-K-0431-6
8. PERFORMING ORGANIZATION NAME AND ADDRESS M.I.T. Francis Bitter National Magnet Laboratory Cambridge, MA 02139		9. CONTRACT OR GRANT NUMBER(S) N00014-84-K-0431
10. CONTROLLING OFFICE NAME AND ADDRESS Office of Naval Research Arlington, VA 22219		11. PROGRAM ELEMENT, PROJECT, TASK AREA & WORK UNIT NUMBERS
12. REPORT DATE 1984		13. NUMBER OF PAGES 14
14. MONITORING AGENCY NAME & ADDRESS (if different from Controlling Office)		15. SECURITY CLASS. (of this report) Unclassified, Unlimited
16. DISTRIBUTION STATEMENT (of this Report) <div style="border: 1px solid black; padding: 5px; text-align: center;">DISTRIBUTION STATEMENT A Approved for public release; Distribution Unlimited</div>		17. SECURITY CLASS. (of the abstract entered in Block 20, if different from Report) DTIC ELECTED S JUL 26 1985 D B
18. SUPPLEMENTARY NOTES To be published in Phys. Rev. B.		
19. KEY WORDS (Continue on reverse side if necessary and identify by block number) High density phenomenon Multiple quantum wells Excitons		
20. ABSTRACT (Continue on reverse side if necessary and identify by block number) A sharp photoluminescence spectral feature has been observed in AlGaAs/GaAs multi-quantum-well structures under high intensity, resonant excitation at the ground state exciton. This feature, which appears below the exciton ground state, emerges from a cold dense system of excitons, but prior to the break-up of excitons into an electron-hole plasma. A collective excitonic state is speculated.		

(accepted for publication
in Physics Review B/
Rapid Communications)

High-density excitonic state in two-dimensional multiquantum wells*

H. Q. Le and S. Lax**

Francis Bitter National Magnet Laboratory

Massachusetts Institute of Technology, Cambridge, Ma 02139

B. A. Vojak[†] and A. R. Calawa

Lincoln Laboratory, Massachusetts Institute of Technology, Lexington, Ma 02173

ABSTRACT

A sharp photoluminescence spectral feature has been observed in AlGaAs/GaAs multi-quantum-well structures under high intensity, resonant excitation at the ground state exciton. This feature, which appears below the exciton ground state, emerges from a cold dense system of excitons, but prior to the break-up of excitons into an electron-hole plasma. A collective excitonic state is speculated.

*This work is supported by the Office of Naval Research; the National Magnet Laboratory is supported by the National Science Foundation and Lincoln Laboratory is supported by the U.S. Air Force.

**Also Physics Department and Lincoln Laboratory

[†]Present address: Amoco Research Center, P. O. Box 400, Naperville, IL 60566

and the corresponding energy gap. In the case of the two-dimensional electron gas, the exciton density is proportional to the carrier density, and the exciton lifetime is finite. Thus, the ultimate creation of an electron-hole Fermi system is inevitable. However, the boundary between a neutral excitonic gas phase which is essentially single particle state, and an electron-hole metallic phase, a many body state, is not well understood, experimentally or theoretically[1,2]. Much less understood is the problem in two dimensions. In this communication, we report the observation of luminescence spectral features from quasi-two-dimensional (Q2D) semiconductor heterostructures under high intensity optical excitation. The observed luminescence spectra bear the characteristics of many body phenomena that appear to be more complex than the two extreme phases mentioned. Using resonant excitation method to generate dense exciton systems, we studied the evolution of luminescence as function of excitation intensity. The emergence of these luminescence lines is described and their nature will be discussed.

The samples are heterostructures grown by molecular beam epitaxy. Excitation was performed with an optically pumped tunable dye laser of 8 nsec pulse duration. Samples were mounted in a dewar whose temperature was varied from 1.8 to over 100 K, and in a magnetic field up to 10 tesla. The incident light was normal to the sample, and focused to a spot $\approx 100 \mu\text{m}$. The luminescence light was detected in two configurations, either normal to or parallel with the MQW plane. In the first configuration, the luminescence is essentially spontaneous, while in the latter some stimulated emission effect may occur due to a longer active length ($\approx 100 \mu\text{m}$). Thus, care was taken to ensure proper experimental observation and interpretation of various luminescence spectra. Light emanating from the entire excited spot was collected, and spectra were somewhat inhomogeneous. The excitation intensity I_{ex} was varied with calibrated neutral density filters. The ab-

and intensity of I_{ex} were determined to within a factor of two, but the relative intensities were determined to within 10%. Luminescence was analyzed with a spectrometer equipped with a 10 cm² integrating sphere and a 10 mm diameter photomultiplier tube equipped with a 50% efficiency photocathode.

Luminescence spectra of excitons normal to the MQW layer plane are shown for Fig. 1 for sample 1. The sample has nominally a 145 Å MQW structure as depicted in the inset. The low intensity absorption spectrum shows the two lowest exciton states, the heavy hole and the single-hole exciton (Fig. 1 (a')). The

large linewidths of these two lines are due to inhomogeneous strains in the thin sample for absorption. Luminescence spectra at low excitation intensity (trace (a)) show the heavy hole exciton recombination (labeled X) as a narrower high energy peak, and other extrinsic structures at lower energy. These characteristic properties of MQW structures under low intensity excitation have been well established[3]. High intensity studies, from 10^4 to 10^6 W/cm², were performed using near or on resonant excitation techniques, i.e., the excitation energy $\hbar\nu_{ex}$ was close to the ground state (heavy hole) exciton energy. Under this condition, excitons are created with very little kinetic energy. When I_{ex} exceeds 10^4 W/cm² (Fig. 1, traces (b)), a new feature, labeled X', emerges at about 6 meV below the heavy hole exciton. The X' linewidth is comparable to or narrower than those of the exciton states. As I_{ex} is further increased, the X' intensity grows much faster than that of X, and X' energy red-shifts slightly, but not very significantly. At an intensity about 30 times the threshold value at which X' emerges, a second structure appears (Fig. 2). This second structure, which rapidly overwhelms X' at still higher I_{ex} , can be presumed to be due to an electron-hole plasma (EHP), since an EHP is the ultimate limit of a high density electron-hole system. Lineshape analysis of the second structure in terms of the EHP theory yields qualitatively the expected behavior and, thus, renders support to this interpretation. The same process was observed in the lumines-

excitation and $I_{ex} < 2 \times 10^3 \text{ W/cm}^2$ a significant luminescence due to the initial excitation. The gain factor across the excited spot was measured and found to be small for $I_{ex} < 2 \times 10^3 \text{ W/cm}^2$. The luminescence in this configuration is then essentially spontaneous. However, at higher I_{ex} , where the EHP condition occurs, there is significant difference between the spectra of the two configurations obtained under identical excitation conditions, thus indicating the effect of stimulated emission on the EHP recombination. As discussed in this communication is the nature of X' .

It is important to establish that X' is a different entity from the EHP. Besides the evidence from the luminescence spectra, excitation spectroscopy also contributes evidence for this distinction, as well as suggests the close connection between X' and exciton. The luminescence detected at X' displays a strong resonance with a sharp low energy edge as the excitation energy $h\nu_{ex}$ is near the heavy hole exciton (Fig. 3). This sharp edge is coincident with the low intensity CW absorption of exciton (Fig. 1 (a')). Although the bleaching of this exciton resonance eventually occurs at very high I_{ex} , it is clear that at the excitation level where X' begins to form, excitons still exist as a defined energy level of the semiconductor. This aspect is a further distinction between X' and EHP. At the electron-hole density where an EHP is formed, excitonic structure is completely bleached out [1,2]. Absorption at the intensity for EHP creation should not show strong excitonic feature. The dependence of X' on $h\nu_{ex}$ also suggests a connection between X' and exciton. As $h\nu_{ex}$ exceeds the exciton energy, X' appears to shift toward lower energy (Fig. 3, trace (b)). However, although evidences were not as obvious as in luminescence spectra, the apparent redshift of X' was probably not real, but due to the emergence of EHP in lieu of X' for $h\nu_{ex}$ larger than a certain value, at a constant I_{ex} . In summary, resonant excitation was found to be the crucial condition for the observation of a sharp and distinct X' , as well as the discernment of a gradual appearance of the

IP recombination close to X' . This indicates that a cold, dense system of excitons is required for the appearance of X' .

For increasing lattice temperature T_L (up to 45 K), the intensity of X' decreases while that of X_1 increases or remains relatively unchanged. This relationship between X' and X_1 intensities vs. T_L is also dependent on I_{ex} . This may suggest that X' and X_1 represent two different phases of a dense excitonic system, in which a temperature shift causes an increase in one population at the expense of the other.

The above experimental results are applicable to a number of samples. Two samples with 145 and 63 Å well width yield the most suggestive data. Table I briefly summarizes the measured characteristics of the experimental results. There are samples which failed to exhibit this kind of heavy-exciton emission; instead, broad band emission extending toward higher energy, i.e., Burstein shift, was observed. We believe that in these samples, optically generated carriers fail to completely relax in energy within their radiative recombination lifetime to form a many body state.

Phenomenologically, somewhat analogous luminescence effects were observed for highly excited bulk GaAs[4,5]. A structure labeled A or P by various authors appeared to be similar to X' , although the latter seems to be more pronounced. The A/P structure has been interpreted [5] as an exciton-exciton (or excitonic polariton) scattering effect. For this case, this model would involve no heavy hole excitons undergoing a collision which leaves a light hole exciton and a photon which becomes X' . However, this model does not appear to be satisfactory to account for X' . A serious objection is based on the Zeeman behavior of various states, shown in Fig. 4. The light hole exciton states split into two resolvable states with opposite polarization. Yet no such corresponding

to the energy range, ΔE , of bands such that $\Delta E \ll \omega_{\text{exc}}$ and $\omega_{\text{exc}} \ll \omega_{\text{ph}}$. Energy of X' , as stipulated by the conservation of energy, was observed. If X' energy could be arbitrarily correlated within a linewidth to either one of X_1 , the deviation (Fig. (4)) is too systematic to accept the hypothesis.

In conclusion, high intensity resonant excitation on MQW structures produces a luminescence feature arising from a cold dense exciton gas, prior to the formation of degenerate electron-hole metallic phases. There have been theoretical studies[6] which predict a first order Mott transition for a 2D Coulomb system from a neutral phase to a plasma phase. The picture from the current experimental work appears to be more complicated than this theoretical study. There appears to be an intermediate state between an exciton gas and an

X' could represent a collective state formed from a system of 2D interacting excitons. A possible boson-boson interaction, i.e., electrons exchanging real or virtual acoustic phonons at certain exciton critical density is a hypothetical consideration. Such systems of interacting excitons appear to form a liquid state prior to the formation of a degenerate electron-hole phase at much higher densities.

This work was supported in part by the Office of Naval Research; Francis Bitter National Magnet Laboratory is supported by the National Science Foundation. The Lincoln Laboratory portion of the work was sponsored by the Department of the Air Force. One of us (H.G.L.) acknowledges receipt of an IBM fellowship. We thank Dr. D. H. Walther for valuable assistance and Dr. A. Korter for fruitful discussions.

REFERENCES

- J. C. Hansel, T. G. Phillips and G. A. Thomas, in Solid State Physics, ed. H. Ehrenreich, F. Seitz, D. Turnbull (Academic Press, N.Y., 1977), Vol .32, and T. M. Rice, ibid., p.1.
- C. Klingshirn and H. Haug, Phys. Rep. 70, 315 (1981).
- For a review, see R. Dingle, in Festkorperprobleme (Advances in Solid State Ics), ed. by H. J. Queisser (Pergamon-Vieweg, Braunschweig, 1975), Vol. XV,
- i. For intrinsic luminescence properties, see e.g. R. C. Miller, L. Kleiman, W. A. Nordland,Jr., and A. C. Gossard, Phys. Rev. 863 (1980) and for extrinsic luminescence properties, see e. g. Lambert, B. Deveaud, A. Regreny and G. Talalaeff, Solid State E. 43, 443 (1982); R. C. Miller, A. C. Gossard, W. T. Tsang and O. Munteanu, Phys. Rev. B25, 3871 (1982).
- E. O. Goebel, K. M. Romanek, H. Weber and G. Mahler, Phys. Rev. 4775 (1978) and references therein.
- T. Moriya and T. Kushida, J. Phys. Soc. Jpn. 43, 1646 (1977) and ibid. 849 (1976).
- M. Kosterlitz, J. Phys. C:Solid State Phys. 10, 3753 (1977); C. Deutsch, Devaud, Phys. Rev. A9, 2598 (1974).

Accession For	
NTIS GRA&I	<input checked="" type="checkbox"/>
DTIC TAB	<input type="checkbox"/>
Unannounced	<input type="checkbox"/>
Justification	
PER LETTER	
By PER CALL	
Distribution/ JC	
Availability Codes	
Dist	Avail and/or Special
A-1	



Table I. Energy (E) and linewidth (Γ) in unit of meV of X' , the heavy hole exciton X_h and the light hole exciton X_L for two samples. Measurements are by optical methods.

b (Å)	X'		X_h		X_L	
	E	Γ	E	Γ	E	Γ
5	1527.5 ± 1	2	1533.5 ± 0.5	1.8	1540.0 ± 0.5	2.5
1	1570 ± 2	5	1582 ± 2	5	$1597 \pm 8^*$	10

nd and complex structure was observed

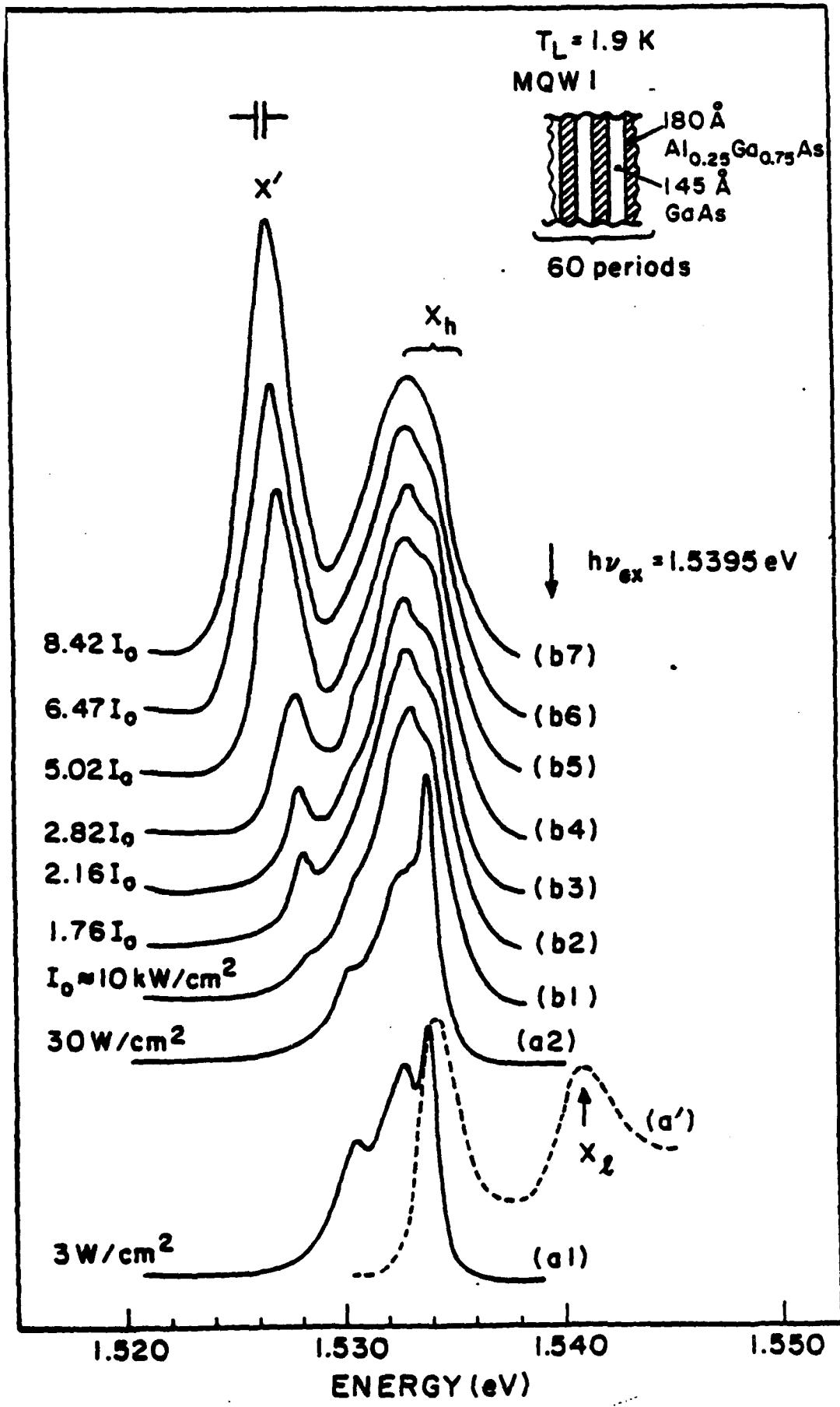
FIGURE CAPTION

(a'): absorption spectrum of MQW 1 at low intensity. X_h and X_l are the heavy hole and the light hole exciton, respectively. (a1): and (a2): luminescence spectra of emission normal to the MQW layer plane (normal configuration) obtained with low intensity, CW 6328 Å laser excitation. The highest energy peak is the heavy hole exciton, and lower energy structures are extrinsic which saturate as I_{ex} is increased. (b): normal configuration luminescence spectra obtained with pulsed dye laser excitation at 1.5395 eV (near resonance excitation), showing X' emergence. (b) were smoothed; some structures are probably not real since they are well within the noise level.

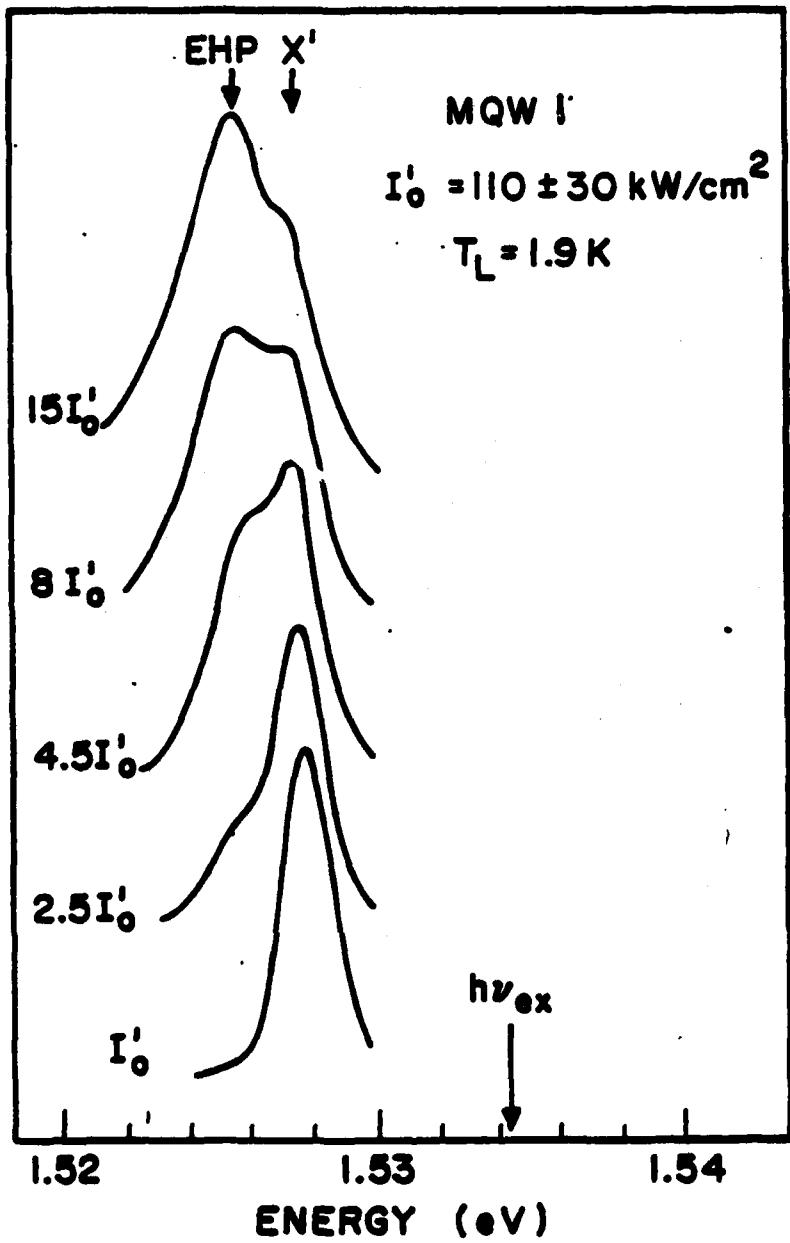
Normal configuration luminescence spectra at still higher excitation intensities where a second structure, identified as due to an EHP, appears and overwhelms X' .

(a) and (b): normal configuration luminescence spectra with $\hbar\nu_{ex} = 1.5395$ eV (near resonance) and 1.92 eV (off resonance), respectively. $I_{ex} = 30 \pm 10$ kW/cm². The structure in (b) may be due to an EHP, thus different from that in (a), which is X' . (c) and (d): excitation spectra, showing X' normal configuration luminescence intensity, collected within the indicated band (1.5 meV wide) as a function of $\hbar\nu_{ex}$. The resonance at the heavy hole exciton X_h is also indicated by an arrow. (d) is vertically shifted for the sake of clarity.

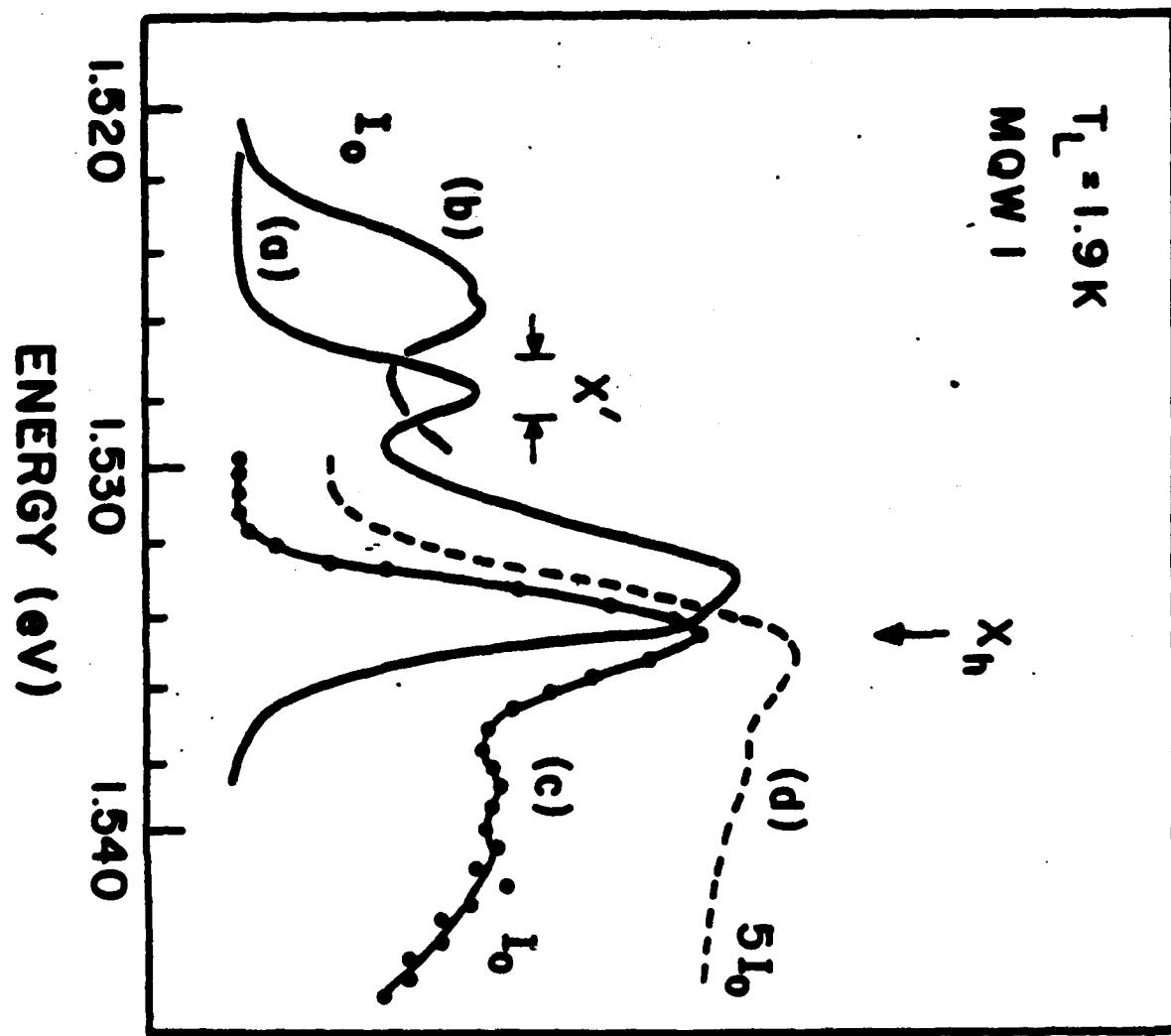
Zeeman shifts of X' , the heavy hole exciton X_h and light hole exciton X_l in MQW 1. Data on X_l were obtained via low intensity excitation spectroscopy. The labels $\pm 3/2, \pm 1/2$ represent spin quantum numbers of the hole. (a) is $2\hbar\nu(X_h) - \hbar\nu(X')$. According to the excitonic scattering model, conservation of energy requires (a) coincide with at least one of the two X_l branches. But the deviation is clearly systematic. (b) is the theoretical calculation of free e-h pair energy.

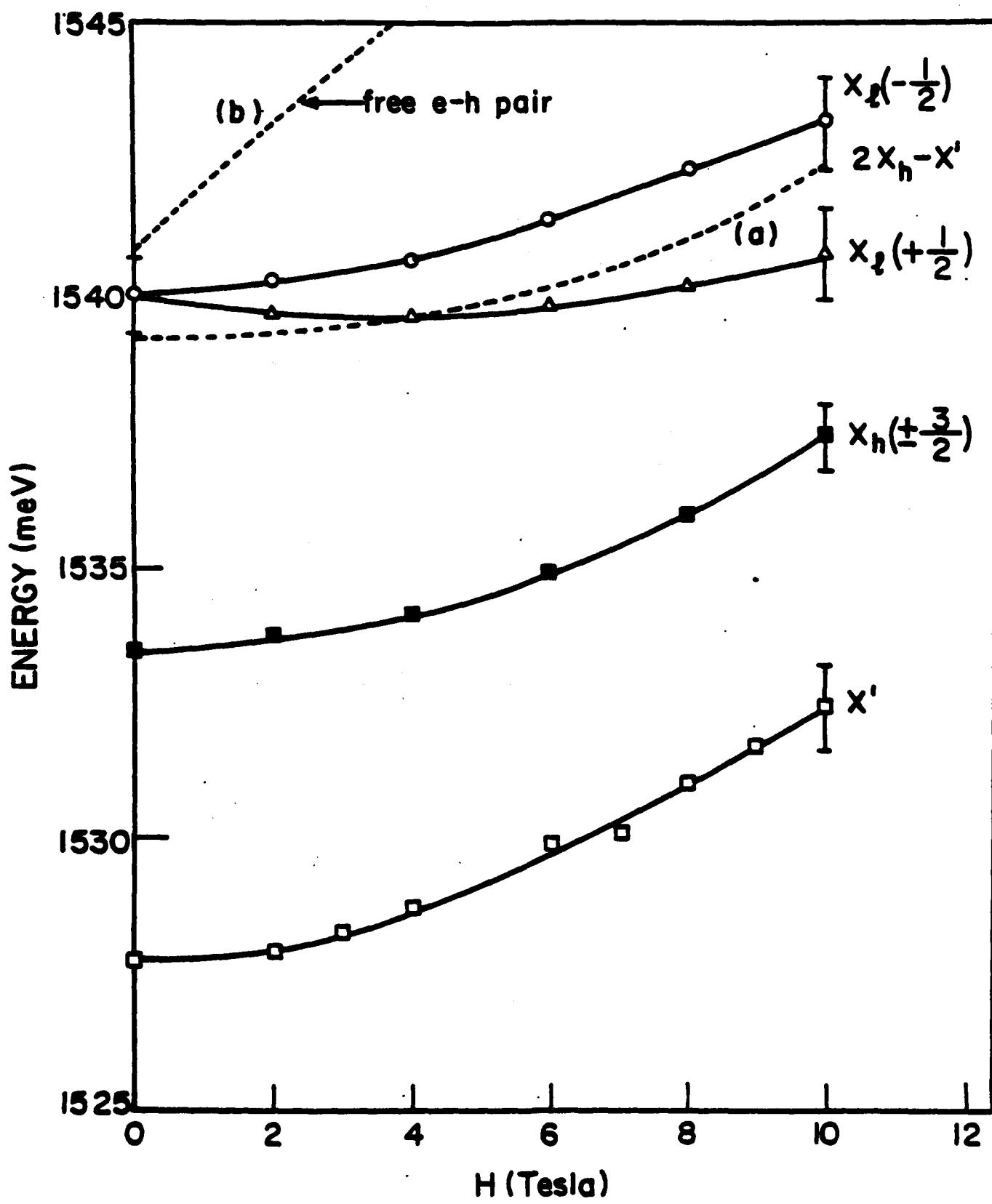


LUMINESCENCE INTENSITY (ARB. UNITS)



LUMINESCENCE INTENSITY (ARB. UNITS)





END

FILMED

9-85

DTIC